

# PRTR5V0U1T

# Ultra low capacitance single rail-to-rail ESD protection Rev. 01 — 25 September 2008 Product da

**Product data sheet** 

### www.DlashedProduct profile

#### 1.1 General description

Ultra low capacitance single rail-to-rail ElectroStatic Discharge (ESD) protection device in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package designed to protect one Hi-Speed data line or high-frequency signal line from the damage caused by ESD and other transients.

PRTR5V0U1T incorporates one ultra low capacitance rail-to-rail protection channel as well as an additional ESD protection diode to ensure signal line protection even if no supply voltage is available.

#### 1.2 Features

- ESD protection of one Hi-Speed data line or high-frequency signal line
- Ultra low input/output to ground capacitance:  $C_{(I/O-GND)} = 1 pF$
- ESD protection up to 8 kV
- IEC 61000-4-2, level 4 (ESD)
- Very low clamping voltage due to an integrated additional ESD protection diode
- Very low reverse current
- Small SMD plastic package

### 1.3 Applications

- USB interfaces (2.0)
- Digital Video Interface (DVI) / High Definition Multimedia Interface (HDMI) interfaces
- Mobile and cordless phones
- Personal Digital Assistants (PDA)
- Digital cameras
- Wide Area Network (WAN) / Local Area Network (LAN) systems
- PCs, notebooks, printers and other PC peripherals





### 1.4 Quick reference data

Table 1. Quick reference data

T<sub>amb</sub> = 25 °C unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per channe	l					
$C_{\text{(I/O-GND)}}$	input/output to ground capacitance	f = 1 MHz; $V_{(I/O-GND)} = 0 V$	<u>[1]</u> _	1	1.5	pF
Zener diode	е					
$V_{RWM}$	reverse standoff voltage		-	-	5.5	V
C <sub>sup</sub>	supply pin to ground capacitance	f = 1 MHz; $V_{CC} = 0 V$	[2] -	16	-	pF

<sup>[1]</sup> Measured from pin 1 to ground.

### 2. Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I/O	input/output		
2	$V_{CC}$	supply voltage	3	3
3	GND	ground	1 2	1 2 006aab111

### 3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
PRTR5V0U1T	-	plastic surface-mounted package; 3 leads	SOT23			

### 4. Marking

Table 4. Marking codes

Type number	Marking code <sup>[1]</sup>
PRTR5V0U1T	ZN*

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

<sup>[2]</sup> Measured from pin 2 to ground.

### 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
T <sub>amb</sub>	ambient temperature		-40	+85	°C
T <sub>stg</sub>	storage temperature		-55	+125	°C

Table 6. ESD maximum ratings

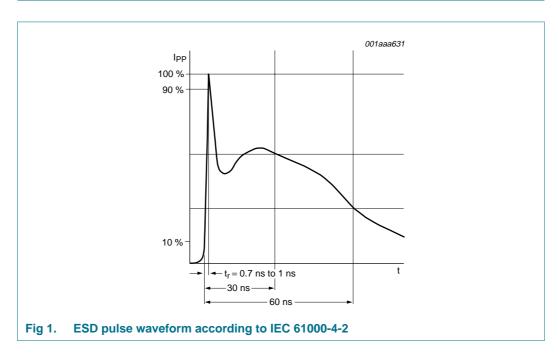
 $T_{amb}$  = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
Per chan	nel					
V <sub>ESD</sub>	electrostatic discharge voltage		[1][2]			
		IEC 61000-4-2; level 4 (contact discharge)		-	8	kV
		MIL-STD-883 (human body model)		-	10	kV

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
Per diode	
IEC 61000-4-2; level 4 (ESD)	> 8 kV (contact)



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<sup>[2]</sup> Measured from pin 1 to 2 or 3.

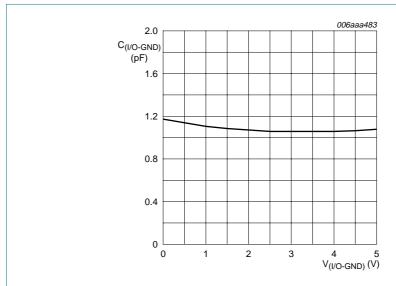
### 6. Characteristics

Table 8. Characteristics

 $T_{amb}$  = 25 °C unless otherwise specified.

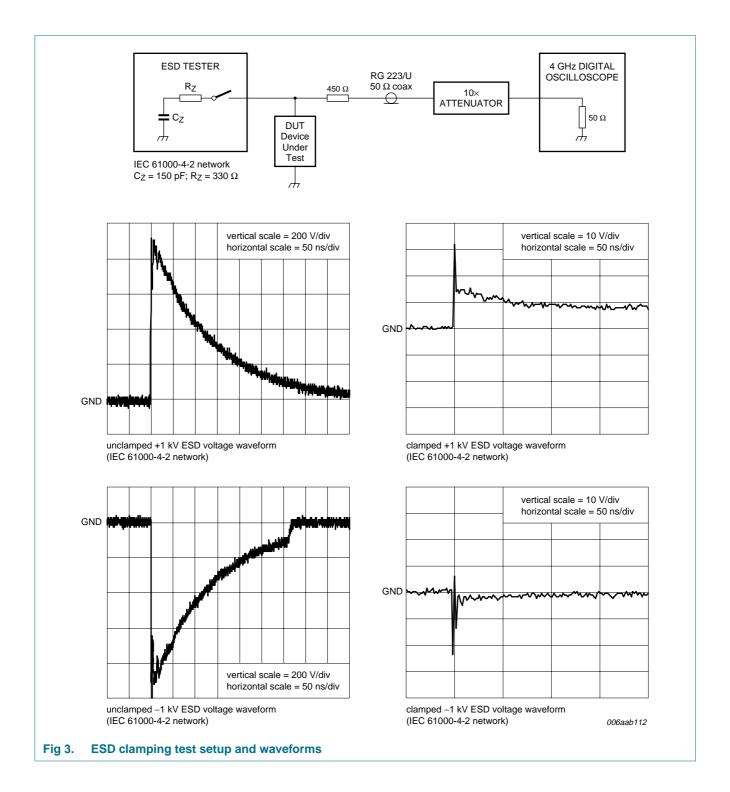
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per channe	el					
I <sub>R</sub>	reverse current	$V_R = 3 V$	<u>[1]</u> _	< 1	100	nA
$C_{\text{(I/O-GND)}}$	input/output to ground capacitance	f = 1 MHz; $V_{(I/O-GND)} = 0 V$	<u>[1]</u> _	1	1.5	pF
$V_{F}$	forward voltage		-	0.7	-	V
Zener diod	le					
$V_{RWM}$	reverse standoff voltage		-	-	5.5	V
$V_{BR}$	breakdown voltage		<u>[2]</u> 6	-	9	V
$C_{sup}$	supply pin to ground capacitance	f = 1 MHz; $V_{CC} = 0 V$	[2] _	16	-	pF

- [1] Measured from pin 1 to ground.
- [2] Measured from pin 2 to ground.



f = 1 MHz;  $T_{amb}$  = 25 °C

Fig 2. Input/output to ground capacitance as a function of input/output to ground voltage; typical values



### 7. Application information

With a capacitance of only 1 pF, the PRTR5V0U1T offers IEC 61000-4-2, level 4 compliant ESD protection.

The PRTR5V0U1T integrates one ultra low capacitance rail-to-rail ESD protection channel and an additional ESD protection diode.

The additional ESD protection diode connected between ground and  $V_{CC}$  prevents charging of the supply.

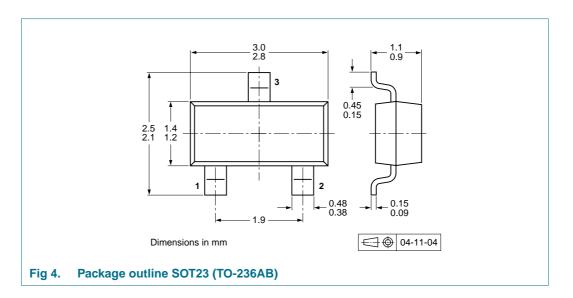
To achieve the maximum ESD protection level, no additional external capacitors are required.

#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PRTR5V0U1T as close to the input terminal or connector as possible.
- 2. The path length between the PRTR5V0U1T and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

### 8. Package outline



### 9. Packing information

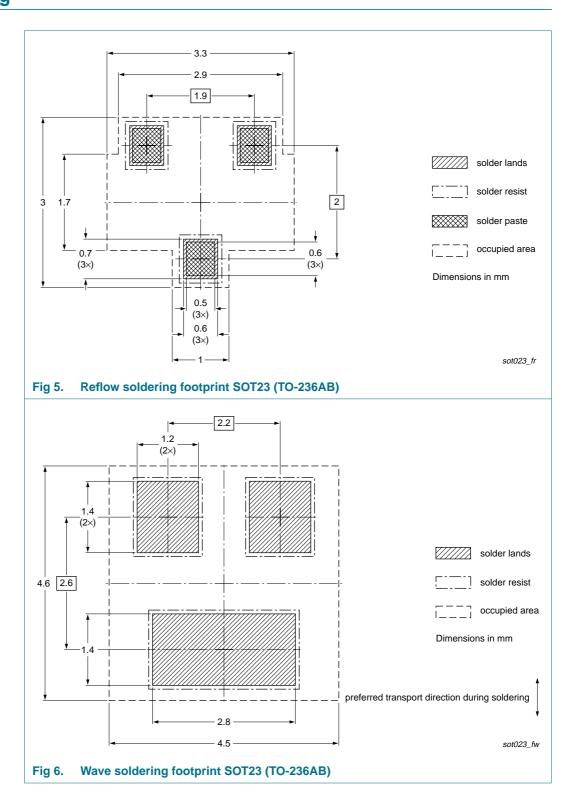
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description Packing quantity		uantity
			3000	10000
PRTR5V0U1T	SOT23	4 mm pitch, 8 mm tape and reel	-215	-235

[1] For further information and the availability of packing methods, see Section 13.

### 10. Soldering





### 11. Revision history

### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PRTR5V0U1T_1	20080925	Product data sheet	-	-

### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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## PRTR5V0U1T

### Ultra low capacitance single rail-to-rail ESD protection

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